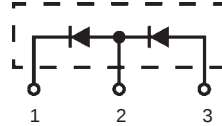


Phase-leg Rectifier Diode

V_{RSM}	V_{RRM}	TO-247 AD	TO-268 AA	ISOPLUS 247™
V	V	Type		
1300	1200	DSP 25-12A	DSP 25-12AT	
1700	1600	DSP 25-16A	DSP 25-16AT	DSP 25-16AR

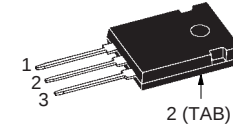


$$V_{RRM} = 1200/1600 \text{ V}$$

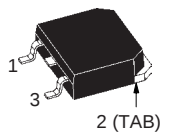
$$I_{F(RMS)} = 2 \times 43 \text{ A}$$

$$I_{F(AV)M} = 2 \times 28 \text{ A}$$

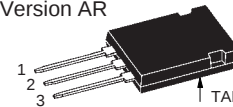
TO-247 AD
Version A



TO-268 AA
Version AT



ISOPLUS 247™
Version AR



1 = Cathode, 2 = Anode/Cathode, 3 = Anode

Features

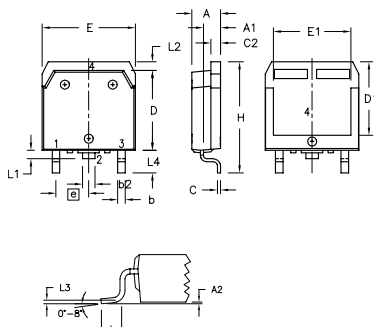
- International standard packages
JEDEC TO-247 AD and TO-268 AA surface mountable
- For single and three phase bridge configuration
- Planar passivated chips
- Epoxy meets UL 94V-0 flammability classification
- Version AR isolated and UL registered E153432

Symbol	Test Conditions	Maximum Ratings
$I_{F(RMS)}$	$T_{VJ} = T_{VJM}$	43 A
$I_{F(AV)M}$	$T_{case} = 100^{\circ}\text{C}; 180^{\circ}$ sine	28 A
I_{FSM}	$T_{VJ} = 45^{\circ}\text{C}; t = 10 \text{ ms}$ (50 Hz), sine	300 A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	330 A
	$T_{VJ} = 150^{\circ}\text{C}; t = 10 \text{ ms}$ (50 Hz), sine	270 A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	300 A
I^2t	$T_{VJ} = 45^{\circ}\text{C}$	450 A ² s
	$t = 8.3 \text{ ms}$ (60 Hz), sine	450 A ² s
	$T_{VJ} = 150^{\circ}\text{C}; t = 10 \text{ ms}$ (50 Hz), sine	340 A ² s
	$t = 8.3 \text{ ms}$ (60 Hz), sine	325 A ² s
T_{VJ}		-40...+180 °C
T_{VJM}		180 °C
T_{stg}		-40...+150 °C
M_d^*	mounting torque M3	0.8...1.2 Nm
F_c	mounting force with clip	20...120 N
V_{ISOL}^{**}	50/60 Hz, RMS, $t = 1$ minute, leads-to-tab	2500 V~
Weight	TO-268 / TO-247	4 / 6 g

* Version A only; ** Version AR only

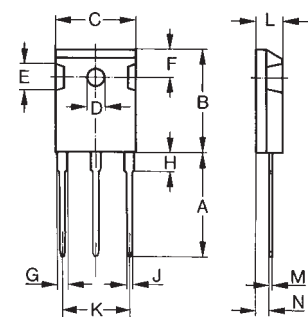
Symbol	Test Conditions	Characteristic Values
I_R	$T_{VJ} = 150^{\circ}\text{C}$ $V_R = V_{RRM}$	$\leq 2 \text{ mA}$
V_F	$I_F = 55 \text{ A}; T_{VJ} = 25^{\circ}\text{C}$	$\leq 1.6 \text{ V}$
V_{T0}	For power-loss calculations only	0.8 V
r_T	$T_{VJ} = T_{VJM}$	15 mΩ
R_{thJC}	DC current	1.5 K/W
R_{thCH}	DC current (with heatsink compound)	0.4 K/W
a	Maximum allowable acceleration	100 m/s ²

TO-268 AA Outline



Dim.	Millimeter Min. Max.	Inches Min. Max.
A	4.9 5.1	.193 .201
A ₁	2.7 2.9	.106 .114
A ₂	.02 .25	.001 .010
b	1.15 1.45	.045 .057
b ₂	1.9 2.1	.75 .83
C	.4 .65	.016 .026
D	13.80 14.00	.543 .551
E	15.85 16.05	.624 .632
E ₁	13.3 13.6	.524 .535
e	5.45 BSC	.215 BSC
H	18.70 19.10	.736 .752
L	2.40 2.70	.094 .106
L1	1.20 1.40	.047 .055
L2	1.00 1.15	.039 .045
L3	0.25 BSC	.010 BSC
L4	3.80 4.10	.150 .161

TO-247 AD and ISOPLUS 247™



Dim.	Millimeter Min. Max.	Inches Min. Max.
A	19.81 20.32	0.780 0.800
B	20.80 21.46	0.819 0.845
C	15.75 16.26	0.610 0.640
D*	3.55 3.65	0.140 0.144
E	4.32 5.49	0.170 0.216
F	5.4 6.2	0.212 0.244
G	1.65 2.13	0.065 0.084
H	- 4.5	- 0.177
J	1.0 1.4	0.040 0.055
K	10.8 11.0	0.426 0.433
L	4.7 5.3	0.185 0.209
M	0.4 0.8	0.016 0.031
N	1.5 2.49	0.087 0.102

* ISOPLUS 247™ without hole

Data according to IEC 60747 and refer to a single diode
IXYS reserves the right to change limits, test conditions and dimensions

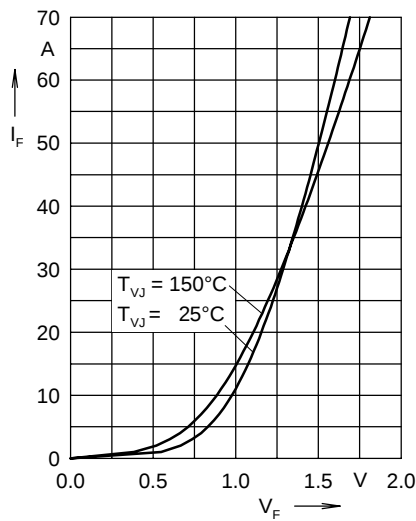


Fig. 1 Forward current versus voltage drop per diode

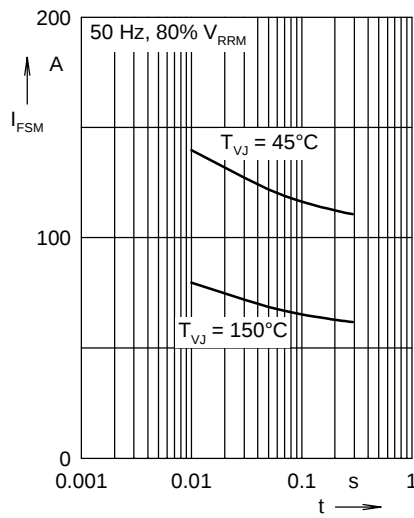


Fig. 2 Surge overload current

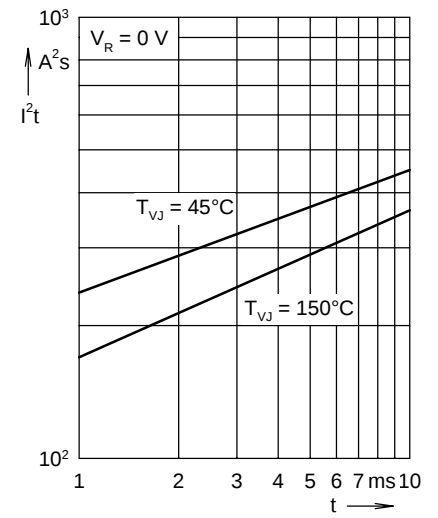


Fig. 3 I^2t versus time per diode

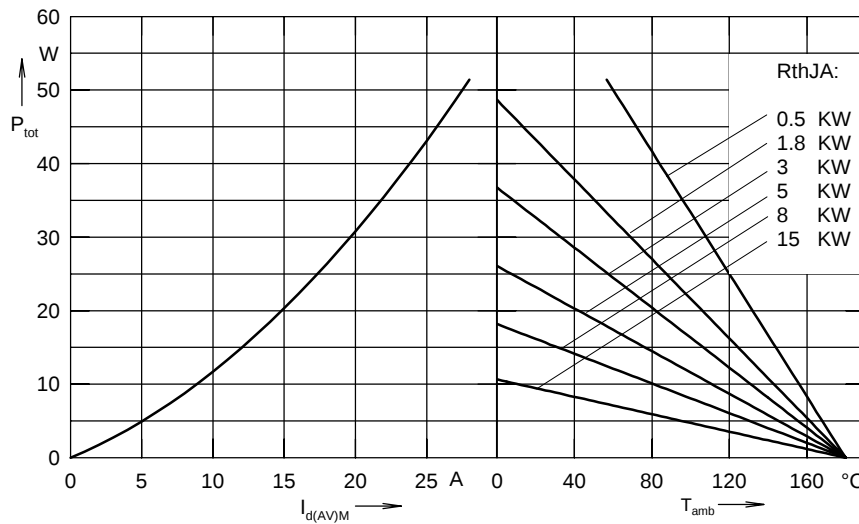


Fig. 4 Power dissipation versus direct output current and ambient temperature, sine 180°

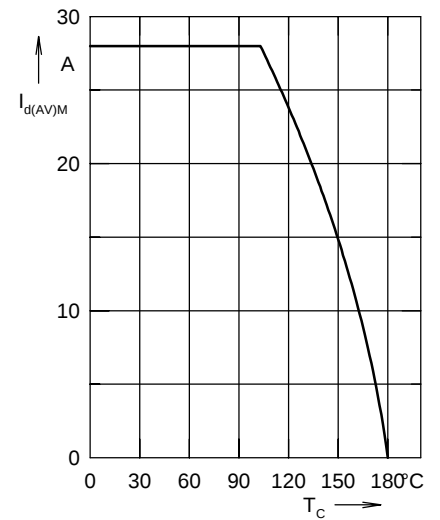


Fig. 5 Max. forward current versus case temperature

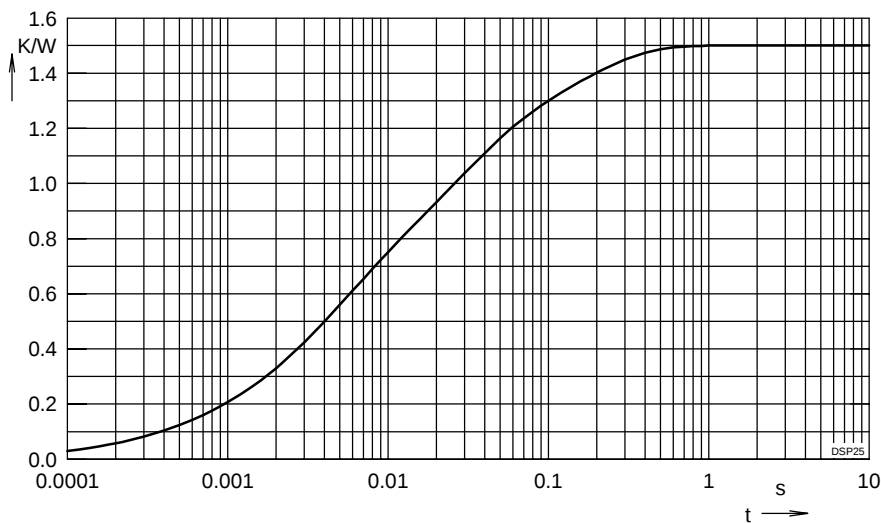


Fig. 6 Transient thermal impedance junction to case

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.06075	0.0004
2	0.183	0.00256
3	0.3405	0.0045
4	0.543	0.0242
5	0.3728	0.15